

HIGH OUTPUT RS-485 TRANSCEIVERS

Check for Samples: [SN65HVD05](#), [SN65HVD06](#), [SN75HVD05](#), [SN65HVD07](#), [SN75HVD06](#), [SN75HVD07](#)

FEATURES

- Minimum Differential Output Voltage of 2.5 V Into a 54-Ω Load
- Open-Circuit, Short-Circuit, and Idle-Bus Failsafe Receiver
- 1/8th Unit-Load Option Available (Up to 256 Nodes on the Bus)
- Bus-Pin ESD Protection Exceeds 16 kV HBM
- Driver Output Slew Rate Control Options
- Electrically Compatible With ANSI TIA/EIA-485-A Standard
- Low-Current Standby Mode: 1 μA Typical
- Glitch-Free Power-Up and Power-Down Protection for Hot-Plugging Applications
- Pin Compatible With Industry Standard SN75176

APPLICATIONS

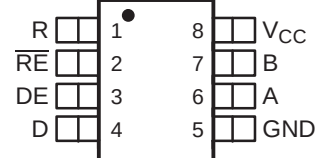
- Data Transmission Over Long or Lossy Lines or Electrically Noisy Environments
- Profibus Line Interface
- Industrial Process Control Networks
- Point-of-Sale (POS) Networks
- Electric Utility Metering
- Building Automation
- Digital Motor Control

DESCRIPTION

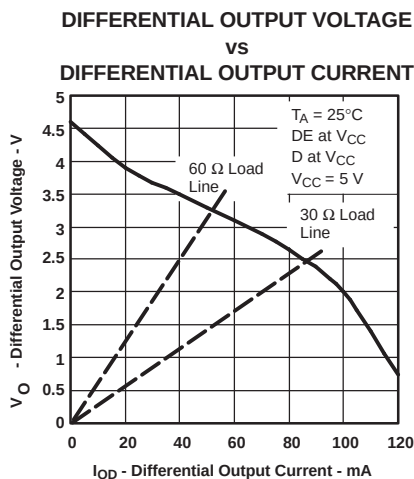
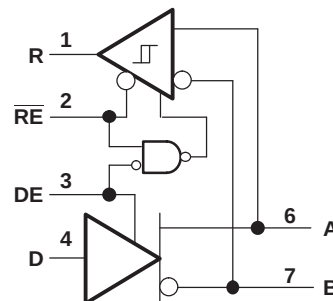
The SN65HVD05, SN75HVD05, SN65HVD06, SN75HVD06, SN65HVD07, and SN75HVD07 combine a 3-state differential line driver and differential line receiver. They are designed for balanced data transmission and interoperate with ANSI TIA/EIA-485-A and ISO 8482E standard-compliant devices. The driver is designed to provide a differential output voltage greater than that required by these standards for increased noise margin. The drivers and receivers have active-high and active-low enables respectively, which can be externally connected together to function as direction control.

The driver differential outputs and receiver differential inputs connect internally to form a differential input/output (I/O) bus port that is designed to offer minimum loading to the bus whenever the driver is disabled or not powered. These devices feature wide positive and negative common-mode voltage ranges, making them suitable for party-line applications.

D OR P PACKAGE
(TOP VIEW)



LOGIC DIAGRAM
(POSITIVE LOGIC)



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

ORDERING INFORMATION⁽¹⁾

SIGNALING RATE	UNIT LOAD	DRIVER OUTPUT SLOPE CONTROL	T _A	PART NUMBER ⁽²⁾		MARKED AS	
						PLASTIC DUAL-IN-LINE PACKAGE (PDIP)	SMALL OUTLINE IC (SOIC) PACKAGE
40 Mbps	1/2	No	–40°C to 85°C	SN65HVD05D	SN65HVD05P	65HVD05	VP05
10 Mbps	1/8	Yes		SN65HVD06D	SN65HVD06P	65HVD06	VP06
1 Mbps	1/8	Yes		SN65HVD07D	SN65HVD07P	65HVD07	VP07
40 Mbps	1/2	No	0°C to 70°C	SN75HVD05D	SN75HVD05P	75HVD05	VN05
10 Mbps	1/8	Yes		SN75HVD06D	SN75HVD06P	75HVD06	VN06
1 Mbps	1/8	Yes		SN75HVD07D	SN75HVD07P	75HVD07	VN07

(1) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI web site at www.ti.com.

(2) The D package is available taped and reeled. Add an R suffix to the device type (i.e., SN65HVD05DR).

PACKAGE DISSIPATION RATINGS

(See [Figure 12](#) and [Figure 13](#))

PACKAGE	T _A ≤ 25°C POWER RATING	DERATING FACTOR ⁽¹⁾ ABOVE T _A = 25°C	T _A = 70°C POWER RATING	T _A = 85°C POWER RATING
D ⁽²⁾	710 mW	5.7 mW/°C	455 mW	369 mW
D ⁽³⁾	1282 mW	10.3 mW/°C	821 mW	667 mW
P	1000 mW	8.0 mW/°C	640 mW	520 mW

(1) This is the inverse of the junction-to-ambient thermal resistance when board-mounted and with no air flow.

(2) Tested in accordance with the Low-K thermal metric definitions of EIA/JESD51-3

(3) Tested in accordance with the High-K thermal metric definitions of EIA/JESD51-7

ABSOLUTE MAXIMUM RATINGS

over operating free-air temperature range unless otherwise noted^{(1) (2)}

SN65HVD05, SN65HVD06, SN65HVD07 SN75HVD05, SN75HVD06, SN75HVD07			
Supply voltage range, V _{CC}		–0.3 V to 6 V	
Voltage range at A or B		–9 V to 14 V	
Input voltage range at D, DE, R or $\overline{RE}$		–0.5 V to V _{CC} + 0.5 V	
Voltage input range, transient pulse, A and B, through 100 Ω (see Figure 11)		–50 V to 50 V	
Receiver output current, I _O		–11 mA to 11mA	
Electrostatic discharge	Human body model ⁽³⁾	A, B, and GND	16 kV
		All pins	4 kV
	Charged-device model ⁽⁴⁾	All pins	1 kV
Continuous total power dissipation		See Dissipation Rating Table	

(1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) All voltage values, except differential I/O bus voltages, are with respect to network ground terminal.

(3) Tested in accordance with JEDEC Standard 22, Test Method A114-A.

(4) Tested in accordance with JEDEC Standard 22, Test Method C101.

RECOMMENDED OPERATING CONDITIONS

		MIN	NOM	MAX	UNIT
Supply voltage, V_{CC}		4.5		5.5	V
Voltage at any bus terminal (separately or common mode) V_I or V_{IC}		-7 ⁽¹⁾		12	V
High-level input voltage, V_{IH}	D, DE, $\overline{RE}$	2			V
Low-level input voltage, V_{IL}	D, DE, $\overline{RE}$			0.8	V
Differential input voltage, V_{ID} (see Figure 7)		-12		12	V
High-level output current, I_{OH}	Driver	-100			mA
	Receiver	-8			
Low-level output current, I_{OL}	Driver			100	mA
	Receiver			8	
Operating free-air temperature, T_A	SN65HVD05	-40		85	°C
	SN65HVD06				
	SN65HVD07				
	SN75HVD05	0		70	°C
	SN75HVD06				
	SN75HVD07				

(1) The algebraic convention, in which the least positive (most negative) limit is designated as minimum is used in this data sheet.

DRIVER ELECTRICAL CHARACTERISTICS

over operating free-air temperature range unless otherwise noted

PARAMETER			TEST CONDITIONS		MIN	TYP ⁽¹⁾	MAX	UNIT
V _{IK}	Input clamp voltage		I _I = −18 mA		−1.5			V
V _{OD}	Differential output voltage		No Load				V _{CC}	V
			R _L = 54 Ω, See Figure 4		2.5			
			V _{test} = −7 V to 12 V, See Figure 2		2.2			
Δ V _{OD}	Change in magnitude of differential output voltage		See Figure 4 and Figure 2		−0.2		0.2	V
V _{OC(SS)}	Steady-state common-mode output voltage		See Figure 3		2.2		3.3	V
ΔV _{OC(SS)}	Change in steady-state common-mode output voltage				−0.1		0.1	V
V _{OC(PP)}	Peak-to-peak common-mode output voltage	HVD05	See Figure 3		600		mV	
		HVD06			500			
		HVD07			900			
I _{OZ}	High-impedance output current		See receiver input currents					
I _I	Input current	D			−100		0	μA
		DE			0		100	
I _{OS}	Short-circuit output current		−7 V ≤ V _O ≤ 12 V		−250		250	mA
C _(diff)	Differential output capacitance		V _{ID} = 0.4 sin (4E6πt) + 0.5 V, DE at 0 V			16		pF
I _{CC}	Supply current	$\overline{RE}$ at V _{CC} , D and DE at V _{CC} , No load		Receiver disabled and driver enabled		9	15	mA
		$\overline{RE}$ at V _{CC} , D at V _{CC} DE at 0 V, No load		Receiver disabled and driver disabled (standby)		1	5	μA
		$\overline{RE}$ at 0 V, D and DE at V _{CC} , No load		Receiver enabled and driver enabled		9	15	mA

(1) All typical values are at 25°C and with a 5-V supply.

DRIVER SWITCHING CHARACTERISTICS

over operating free-air temperature range unless otherwise noted

PARAMETER		TEST CONDITIONS	MIN	TYP ⁽¹⁾	MAX	UNIT
t_{PLH}	Propagation delay time, low-to-high-level output	HVD05		6.5	11	ns
		HVD06		27	40	
		HVD07		250	400	
t_{PHL}	Propagation delay time, high-to-low-level output	HVD05		6.5	11	ns
		HVD06		27	40	
		HVD07		250	400	
t_r	Differential output signal rise time	HVD05	2.7	3.6	6	ns
		HVD06	18	28	55	
		HVD07	150	300	450	
t_f	Differential output signal fall time	HVD05	2.7	3.6	6	ns
		HVD06	18	28	55	
		HVD07	150	300	450	
$t_{sk(p)}$	Pulse skew ($ t_{PHL} - t_{PLH} $)	HVD05		2		ns
		HVD06		2.5		
		HVD07		10		
$t_{sk(pp)}^{(2)}$	Part-to-part skew	HVD05		3.5		ns
		HVD06		14		
		HVD07		100		
t_{PZH1}	Propagation delay time, high-impedance-to-high-level output	HVD05		25		ns
		HVD06		45		
		HVD07		250		
t_{PHZ}	Propagation delay time, high-level-to-high-impedance output	HVD05		25		ns
		HVD06		60		
		HVD07		250		
t_{PZL1}	Propagation delay time, high-impedance-to-low-level output	HVD05		15		ns
		HVD06		45		
		HVD07		200		
t_{PLZ}	Propagation delay time, low-level-to-high-impedance output	HVD05		14		ns
		HVD06		90		
		HVD07		550		
t_{PZH2}	Propagation delay time, standby-to-high-level output	$R_L = 110\Omega$, $\overline{RE}$ at 3 V, See Figure 5			6	μs
t_{PZL2}	Propagation delay time, standby-to-low-level output	$R_L = 110\Omega$, $\overline{RE}$ at 3 V, See Figure 6			6	μs

(1) All typical values are at 25°C and with a 5-V supply.

(2) $t_{sk(pp)}$ is the magnitude of the difference in propagation delay times between any specified terminals of two devices when both devices operate with the same supply voltages, at the same temperature, and have identical packages and test circuits.

RECEIVER ELECTRICAL CHARACTERISTICS

over operating free-air temperature range unless otherwise noted

PARAMETER		TEST CONDITIONS		MIN	TYP ⁽¹⁾	MAX	UNIT
V _{IT+}	Positive-going input threshold voltage	I _O = –8 mA				–0.01	V
V _{IT–}	Negative-going input threshold voltage	I _O = 8 mA		–0.2			
V _{hys}	Hysteresis voltage (V _{IT+} – V _{IT–})				35		mV
V _{IK}	Enable-input clamp voltage	I _I = –18 mA		–1.5			V
V _{OH}	High-level output voltage	V _{ID} = 200 mV, I _{OH} = –8 mA, See Figure 7		4			V
V _{OL}	Low-level output voltage	V _{ID} = –200 mV, I _{OL} = 8 mA, See Figure 7				0.4	V
I _{OZ}	High-impedance-state output current	V _O = 0 or V _{CC} $\overline{\text{RE}}$ at V _{CC}		–1		1	μA
I _I	Bus input current	HVD05 Other input at 0 V	V _A or V _B = 12 V		0.23	0.5	mA
			V _A or V _B = 12 V, V _{CC} = 0 V		0.3	0.5	
			V _A or V _B = –7 V	–0.4	0.13		
			V _A or V _B = –7 V, V _{CC} = 0 V	–0.4	0.15		
	Bus input current	HVD06 HVD07 Other input at 0 V	V _A or V _B = 12 V		0.06	0.1	mA
			V _A or V _B = 12 V, V _{CC} = 0 V		0.08	0.13	
			V _A or V _B = –7 V	–0.1	0.05		
			V _A or V _B = –7 V, V _{CC} = 0 V	–0.05	0.03		
I _{IH}	High-level input current, $\overline{\text{RE}}$	V _{IH} = 2 V		–60	26.4		μA
I _{IL}	Low-level input current, $\overline{\text{RE}}$	V _{IL} = 0.8 V		–60	27.4		μA
C _(diff)	Differential input capacitance	V _I = 0.4 sin (4E6πt) + 0.5 V, DE at 0 V			16		pF
I _{CC}	Supply current	$\overline{\text{RE}}$ at 0 V, D and DE at 0 V, No load	Receiver enabled and driver disabled		5	10	mA
		$\overline{\text{RE}}$ at V _{CC} , DE at 0 V, D at V _{CC} , No load	Receiver disabled and driver disabled (standby)		1	5	μA
		$\overline{\text{RE}}$ at 0 V, D and DE at V _{CC} , No load	Receiver enabled and driver enabled		9	15	mA

(1) All typical values are at 25°C and with a 5-V supply.

RECEIVER SWITCHING CHARACTERISTICS

over operating free-air temperature range unless otherwise noted

PARAMETER			TEST CONDITIONS	MIN	TYP ⁽¹⁾	MAX	UNIT
t_{PLH}	Propagation delay time, low-to-high-level output 1/2 UL	HVD05	$V_{ID} = -1.5\text{ V to }1.5\text{ V}$, $C_L = 15\text{ pF}$, See Figure 8		14.6	25	ns
t_{PHL}	Propagation delay time, high-to-low-level output 1/2 UL	HVD05			14.6	25	ns
t_{PLH}	Propagation delay time, low-to-high-level output 1/8 UL	HVD06			55	70	ns
		HVD07			55	70	
t_{PHL}	Propagation delay time, high-to-low-level output 1/8 UL	HVD06			55	70	ns
		HVD07			55	70	
$t_{sk(p)}$	Pulse skew ($ t_{PHL} - t_{PLH} $)	HVD05				2	ns
		HVD06				4.5	
		HVD07				4.5	
$t_{sk(pp)}^{(2)}$	Part-to-part skew	HVD05				6.5	ns
		HVD06				14	
		HVD07				14	
t_r	Output signal rise time		$C_L = 15\text{ pF}$, See Figure 8		2	3	ns
t_f	Output signal fall time				2	3	
t_{PZH1}	Output enable time to high level		$C_L = 15\text{ pF}$, DE at 3 V, See Figure 9			10	ns
t_{PZL1}	Output enable time to low level					10	
t_{PHZ}	Output disable time from high level					15	
t_{PLZ}	Output disable time from low level					15	
t_{PZH2}	Propagation delay time, standby-to-high-level output		$C_L = 15\text{ pF}$, DE at 0, See Figure 10			6	μs
t_{PZL2}	Propagation delay time, standby-to-low-level output					6	

(1) All typical values are at 25°C and with a 5-V supply.

(2) $t_{sk(pp)}$ is the magnitude of the difference in propagation delay times between any specified terminals of two devices when both devices operate with the same supply voltages, at the same temperature, and have identical packages and test circuits.

PARAMETER MEASUREMENT INFORMATION

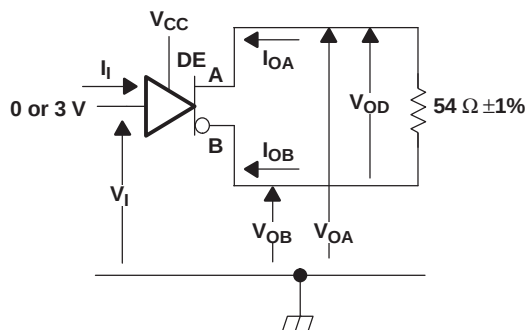


Figure 1. Driver V_{OD} Test Circuit and Voltage and Current Definitions

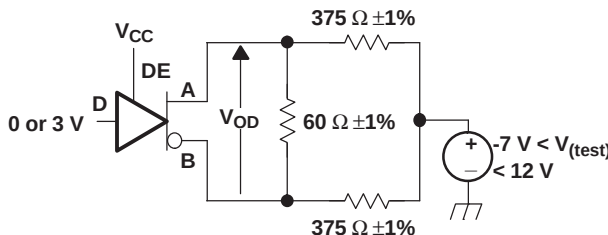
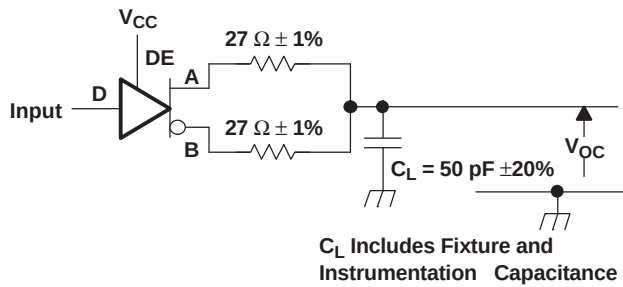
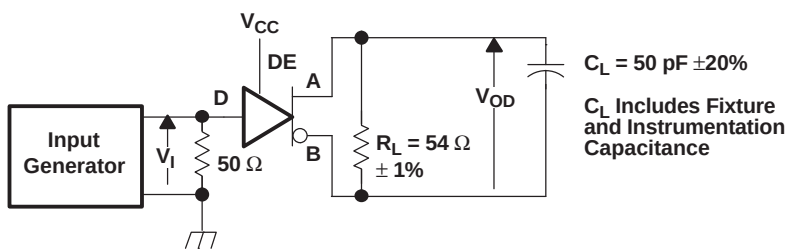


Figure 2. Driver V_{OD} With Common-Mode Loading Test Circuit



Input: PRR = 500 kHz, 50% Duty Cycle, $t_r < 6$ ns, $t_f < 6$ ns, $Z_o = 50 \Omega$

Figure 3. Test Circuit and Definitions for the Driver Common-Mode Output Voltage



Generator: PRR = 500 kHz, 50% Duty Cycle, $t_r < 6$ ns, $t_f < 6$ ns, $Z_o = 50 \Omega$

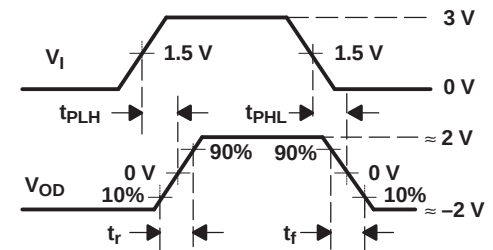
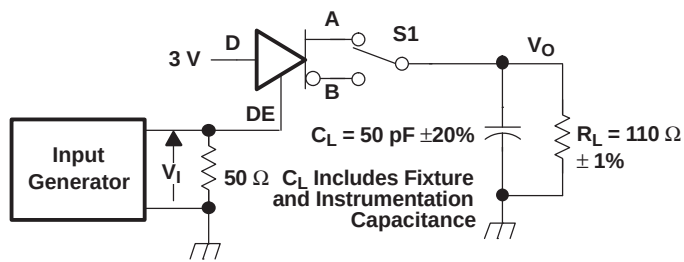


Figure 4. Driver Switching Test Circuit and Voltage Waveforms



Generator: PRR = 100 kHz, 50% Duty Cycle, $t_r < 6$ ns, $t_f < 6$ ns, $Z_o = 50 \Omega$

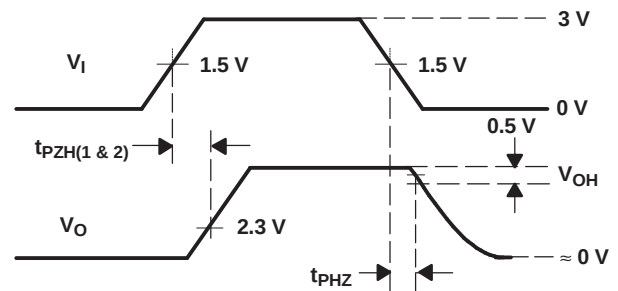
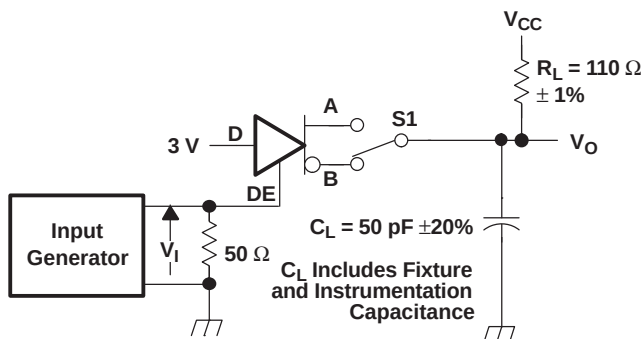


Figure 5. Driver High-Level Enable and Disable Time Test Circuit and Voltage Waveforms



Generator: PRR = 100 kHz, 50% Duty Cycle, $t_r < 6$ ns, $t_f < 6$ ns, $Z_o = 50 \Omega$

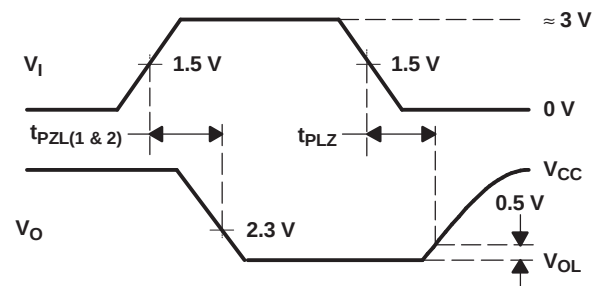


Figure 6. Driver Low-Level Output Enable and Disable Time Test Circuit and Voltage Waveforms

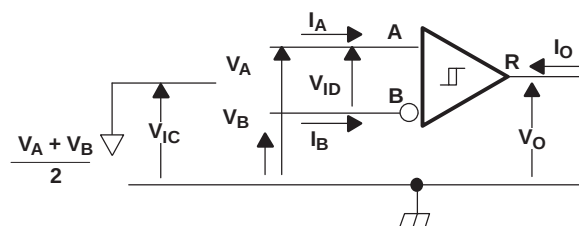


Figure 7. Receiver Voltage and Current Definitions

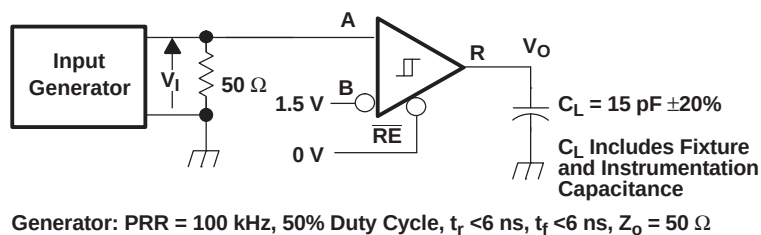


Figure 8. Receiver Switching Test Circuit and Voltage Waveforms

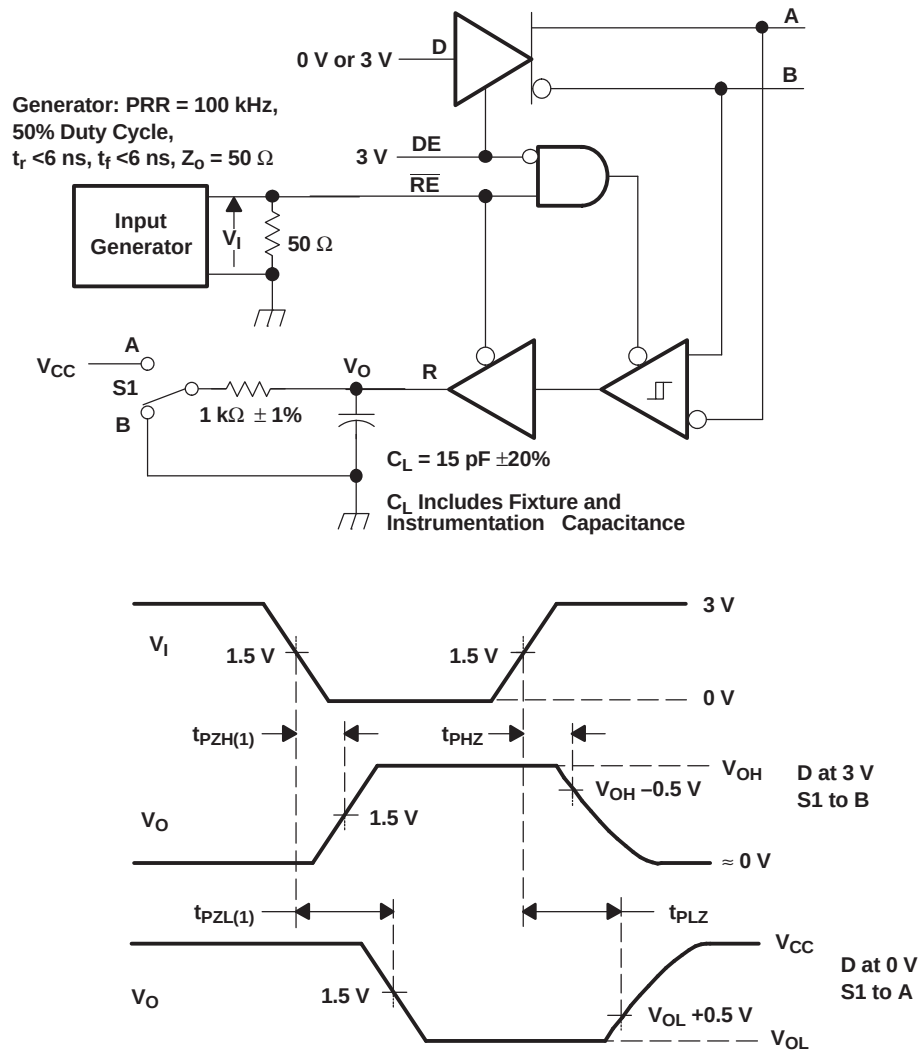


Figure 9. Receiver Enable and Disable Time Test Circuit and Voltage Waveforms With Drivers Enabled

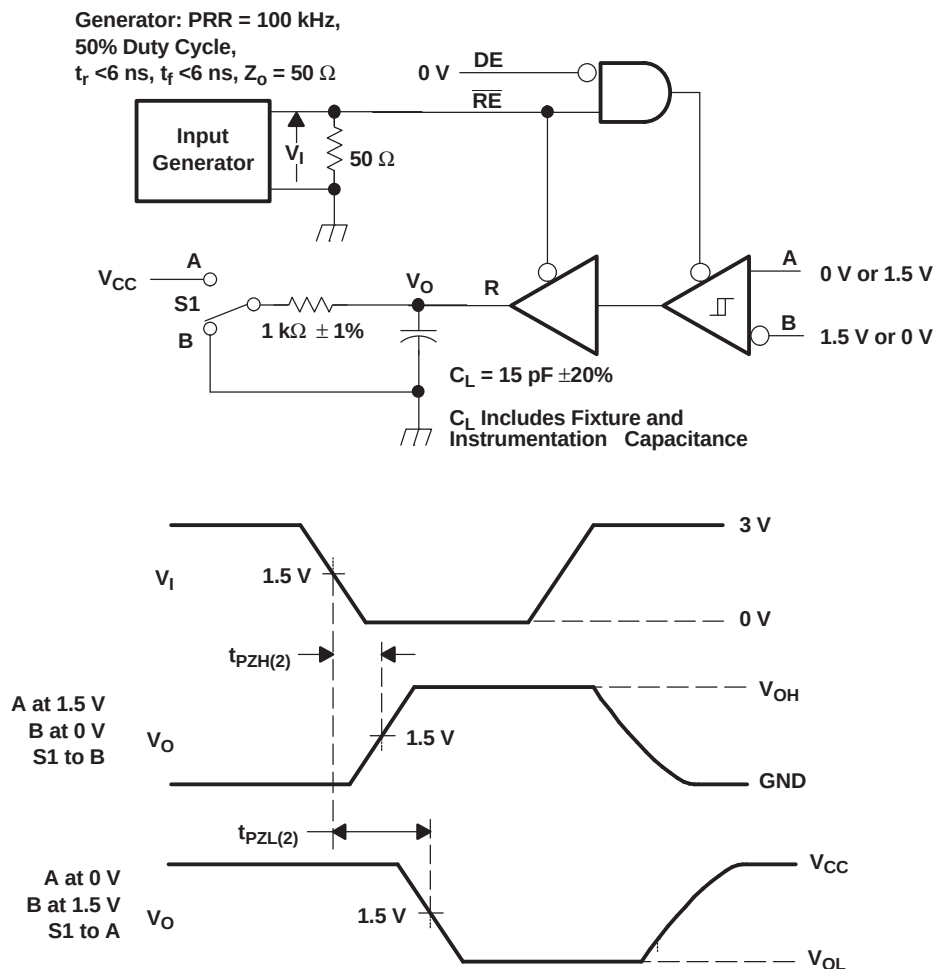
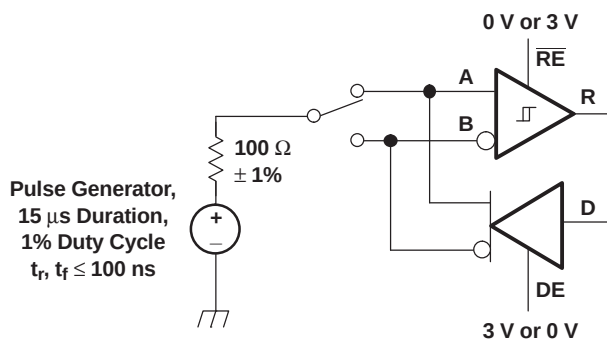


Figure 10. Receiver Enable Time From Standby (Driver Disabled)



NOTE: This test is conducted to test survivability only. Data stability at the R output is not specified.

Figure 11. Test Circuit, Transient Over Voltage Test

FUNCTION TABLES

Table 1. DRIVER

INPUT	ENABLE	OUTPUTS	
D	DE	A	B
H	H	H	L
L	H	L	H
X	L	Z	Z
Open	H	H	L
X	Open	Z	Z

Table 2. RECEIVER⁽¹⁾

DIFFERENTIAL INPUTS	ENABLE	OUTPUT
$V_{ID} = V_A - V_B$	$\overline{RE}$	R
$V_{ID} \leq -0.2\text{ V}$	L	L
$-0.2\text{ V} < V_{ID} < -0.01\text{ V}$	L	?
$-0.01\text{ V} \leq V_{ID}$	L	H
X	H	Z
Open Circuit	L	H
Short Circuit	L	H
IDLE Bus	L	H
X	Open	Z

(1) H = high level; L = low level; Z = high impedance; X = irrelevant;
? = indeterminate

Receiver Failsafe

The differential receiver is “failsafe” to invalid bus states caused by:

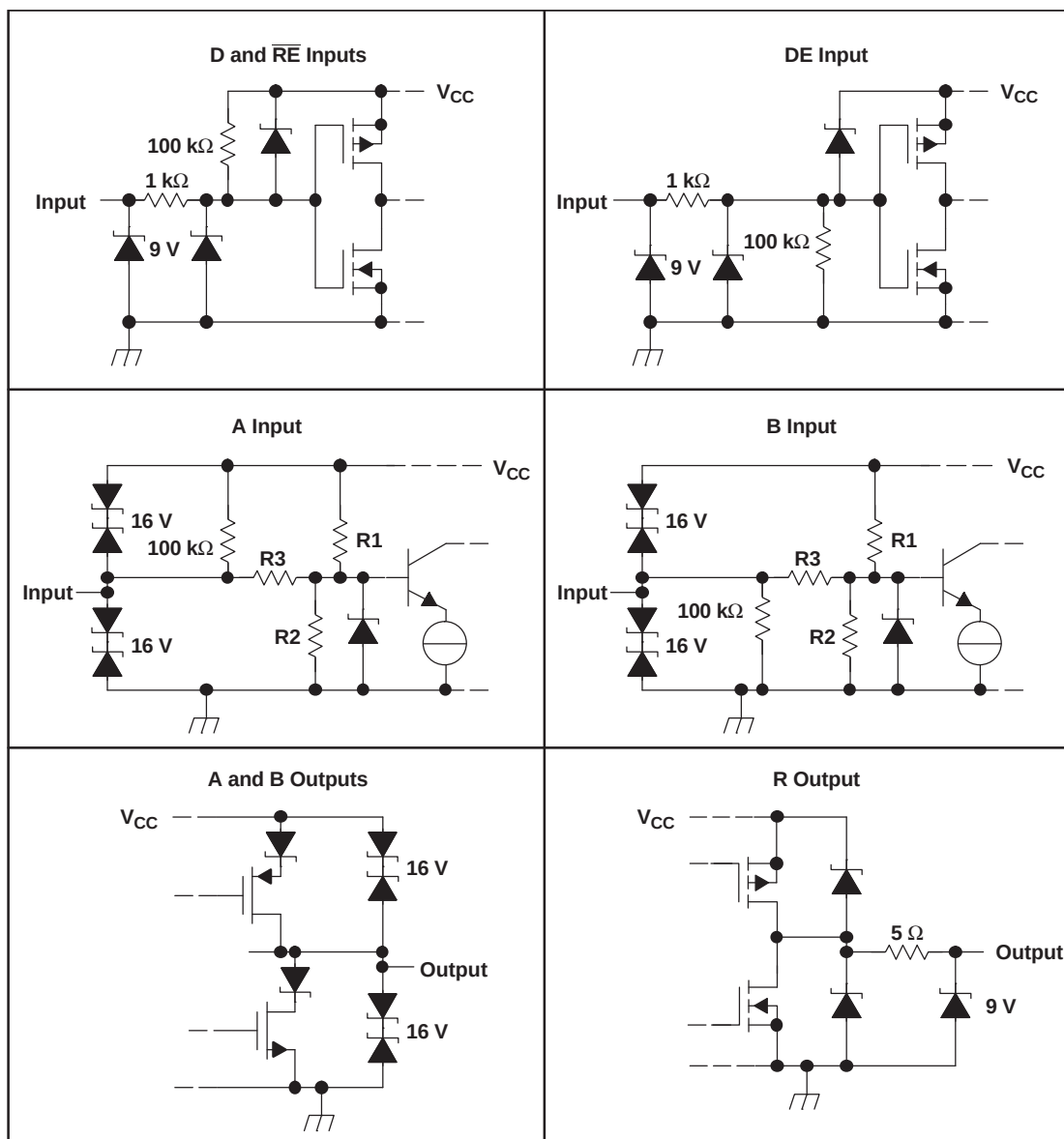
- open bus conditions such as a disconnected connector,
- shorted bus conditions such as cable damage shorting the twisted-pair together, or
- idle bus conditions that occur when no driver on the bus is actively driving

In any of these cases, the differential receiver outputs a failsafe logic High state, so that the output of the receiver is not indeterminate.

Receiver failsafe is accomplished by offsetting the receiver thresholds so that the “input indeterminate” range does not include zero volts differential. To comply with the RS-422 and RS-485 standards, the receiver output *must* output a High when the differential input V_{ID} is more positive than +200 mV, and *must* output a Low when the V_{ID} is more negative than -200 mV. The receiver parameters which determine the failsafe performance are V_{IT+} and V_{IT-} and V_{HYS} . As seen in the [Receiver Electrical Characteristics](#) table, differential signals more negative than -200 mV will always cause a Low receiver output. Similarly, differential signals more positive than +200 mV will *always* cause a High receiver output.

When the differential input signal is close to zero, it will still be above the V_{IT+} threshold, and the receiver output is High. Only when the differential input is more negative than V_{IT-} will the receiver output transition to a Low state. So, the noise immunity of the receiver inputs during a bus fault condition includes the receiver hysteresis value V_{HYS} (the separation between V_{IT+} and V_{IT-}) as well as the value of V_{IT+} .

EQUIVALENT INPUT AND OUTPUT SCHEMATIC DIAGRAMS



	R1/R2	R3
SN65HVD05	9 kΩ	45 kΩ
SN65HVD06	36 kΩ	180 kΩ
SN65HVD07	36 kΩ	180 kΩ

TYPICAL CHARACTERISTICS

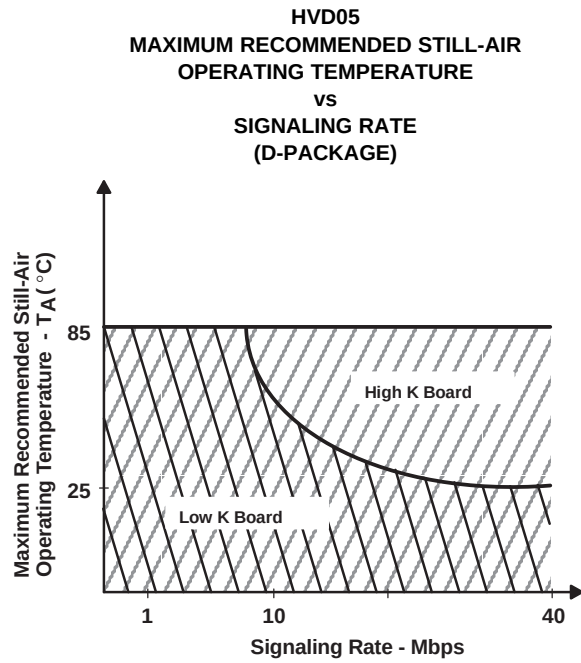


Figure 12.

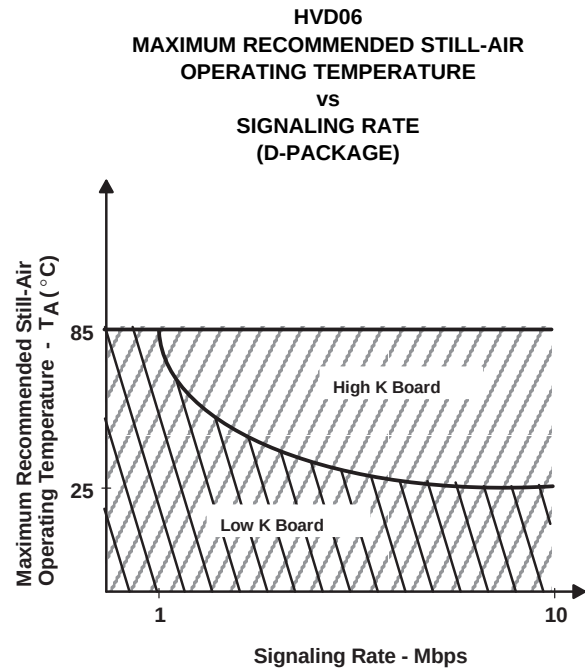


Figure 13.

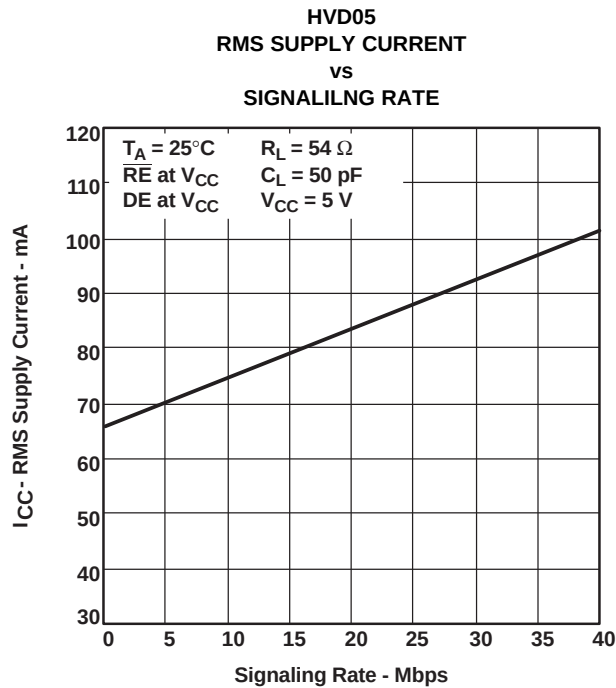


Figure 14.

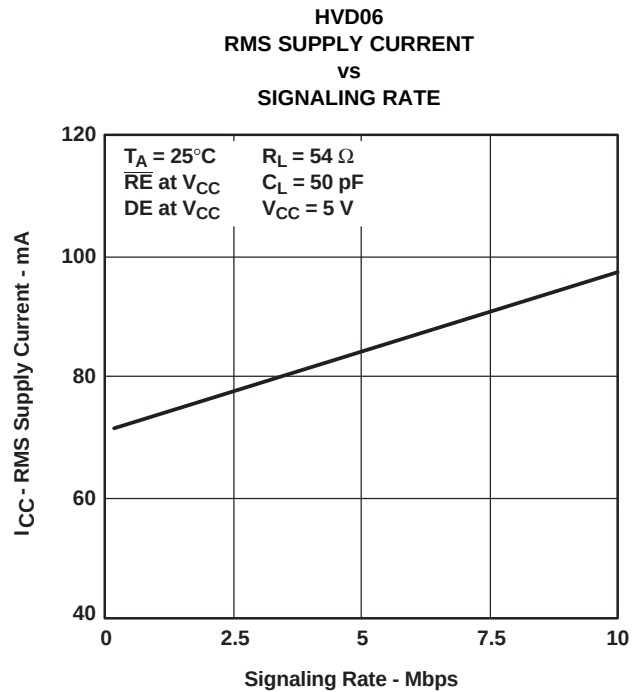


Figure 15.

TYPICAL CHARACTERISTICS (continued)

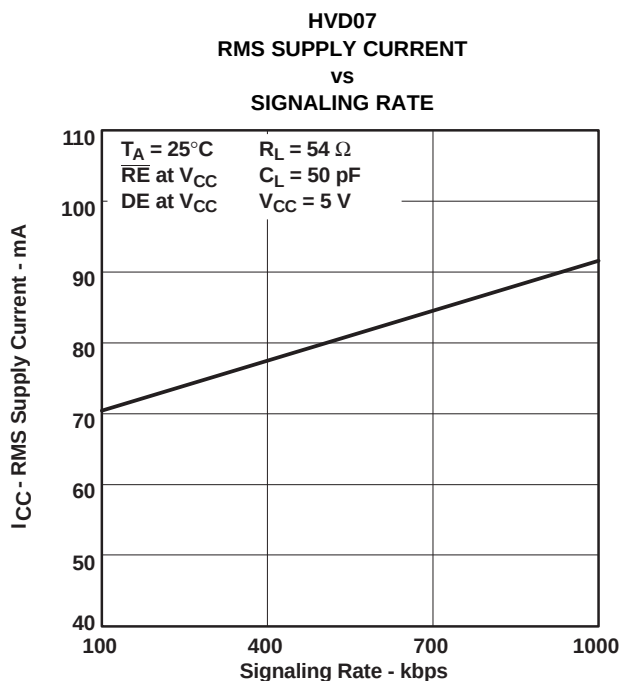


Figure 16.

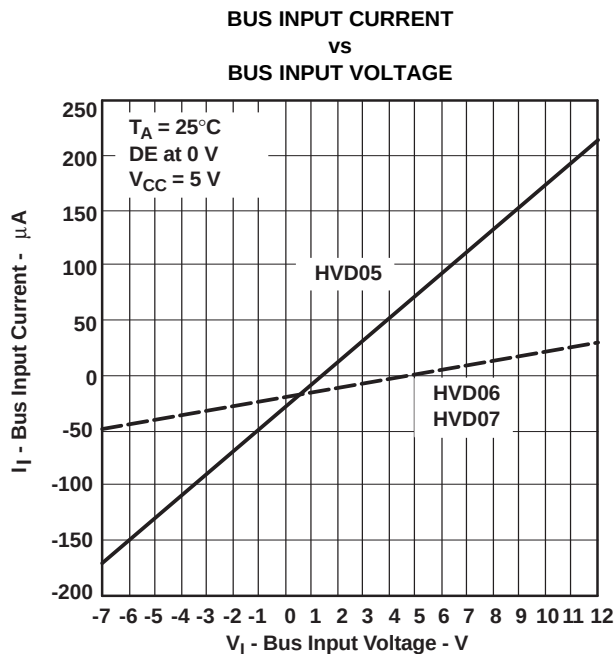


Figure 17.

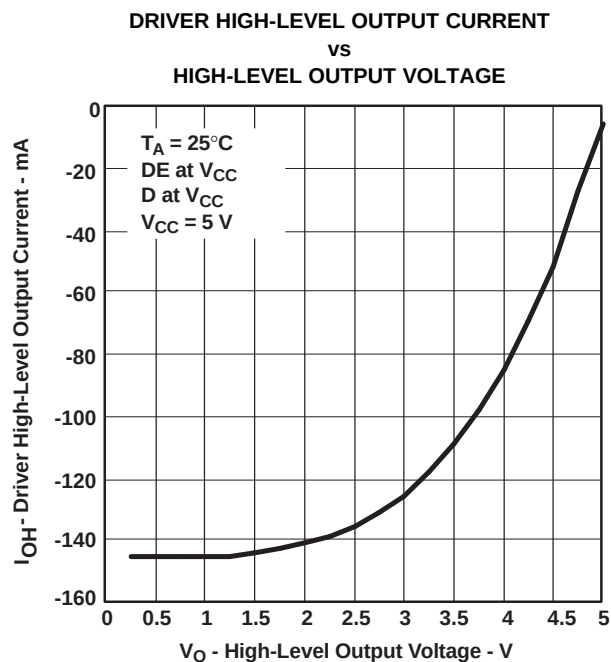


Figure 18.

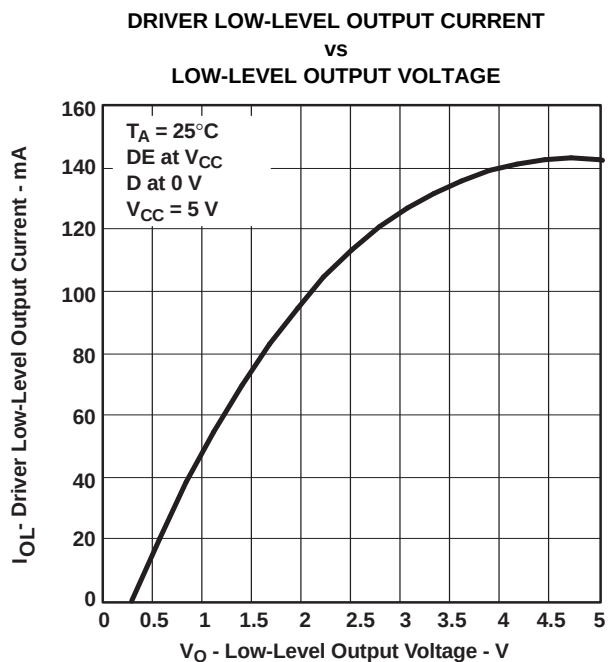


Figure 19.

TYPICAL CHARACTERISTICS (continued)

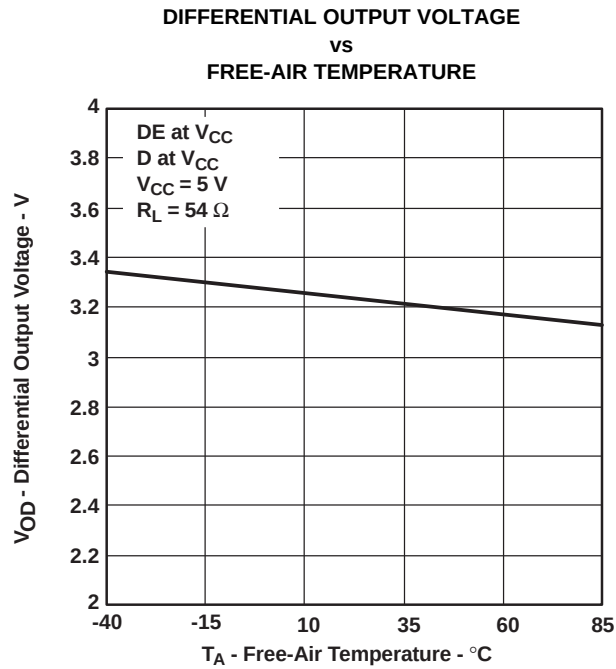


Figure 20.

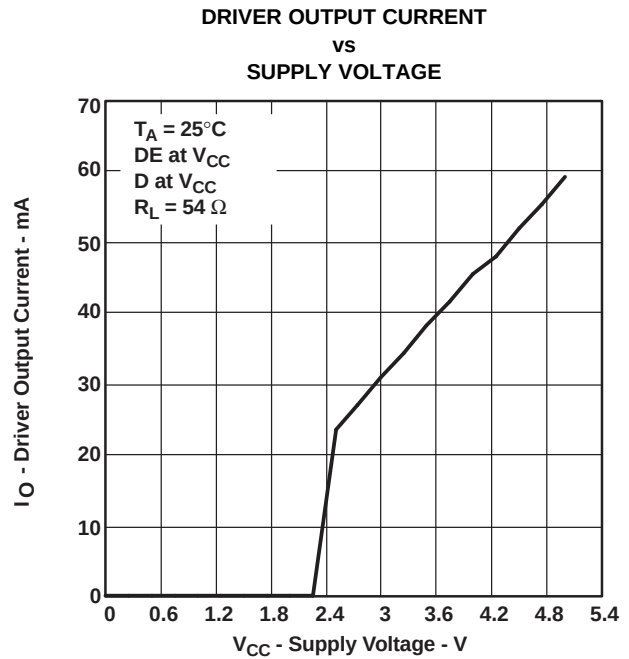


Figure 21.

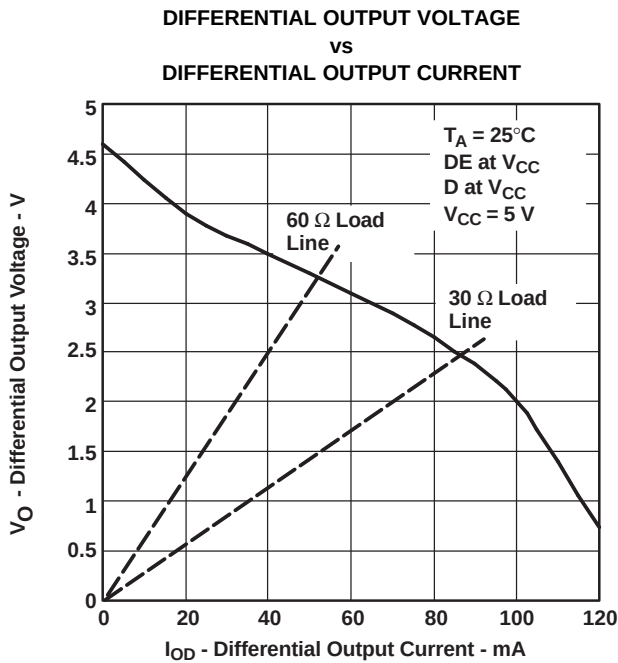


Figure 22.

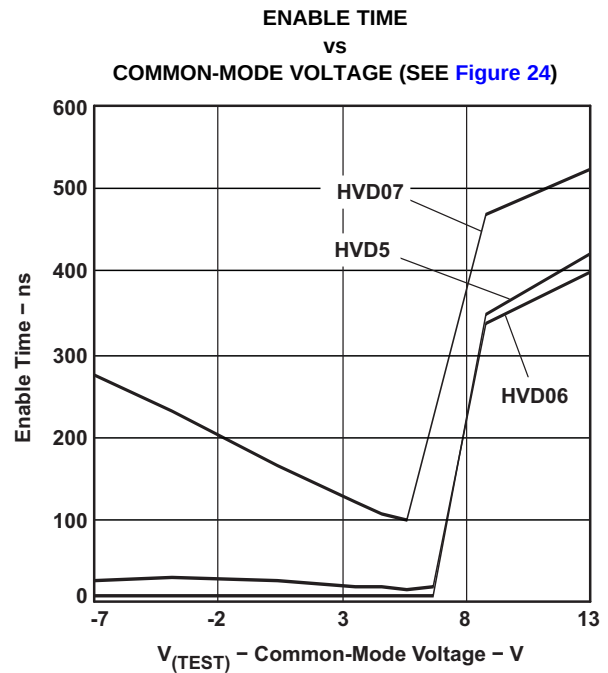


Figure 23.

TYPICAL CHARACTERISTICS (continued)

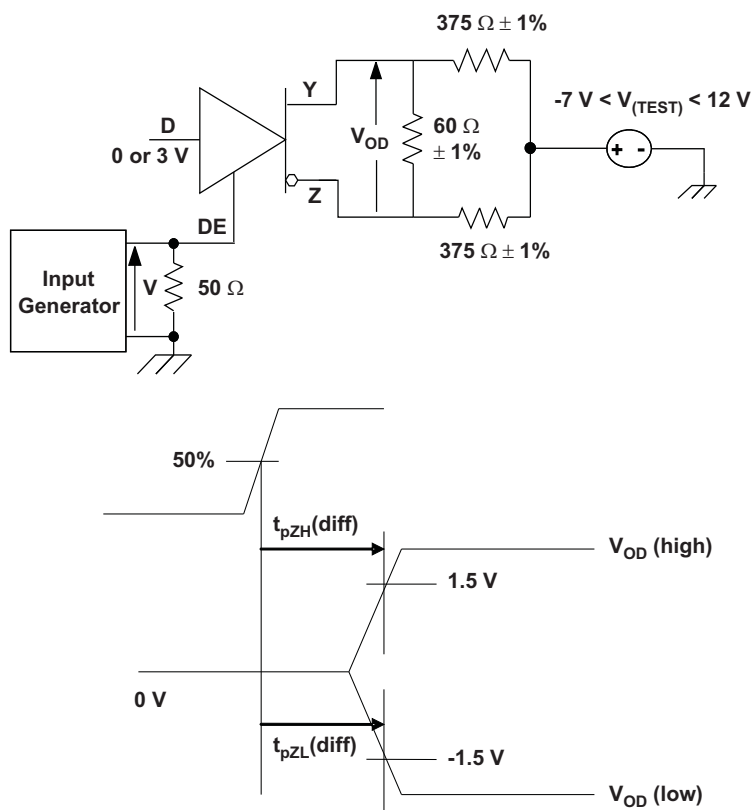
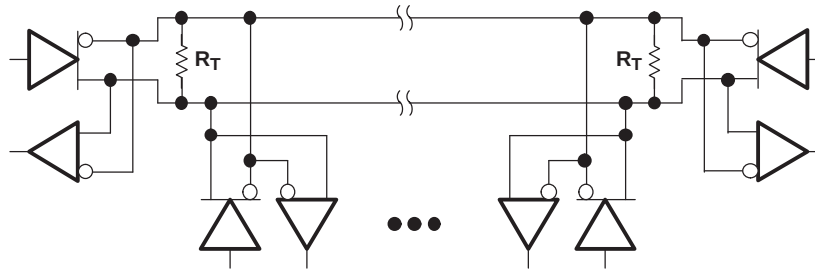


Figure 24. Driver Enable Time From DE to V_{OD}

The time $t_{pZL}(x)$ is the measure from DE to $V_{OD}(x)$. V_{OD} is valid when it is greater than 1.5 V.

APPLICATION INFORMATION



Device	Number of Devices on Bus
HVD05	64
HVD06	256
HVD07	256

NOTE: The line should be terminated at both ends with its characteristic impedance ($R_T = Z_O$).
Stub lengths off the main line should be kept as short as possible.

Figure 25. Typical Application Circuit

REVISION HISTORY

Changes from Revision D (July 2006) to Revision E	Page
• Added IDLE Bus to the Receivers Function Table	11
• Added the Receiver Failsafe paragraph.	11

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
SN65HVD05D	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	VP05	Samples
SN65HVD05DG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	VP05	Samples
SN65HVD05DR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	VP05	Samples
SN65HVD05DRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	VP05	Samples
SN65HVD05P	ACTIVE	PDIP	P	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-40 to 85	65HVD05	Samples
SN65HVD05PE4	ACTIVE	PDIP	P	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-40 to 85	65HVD05	Samples
SN65HVD06D	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	VP06	Samples
SN65HVD06DG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	VP06	Samples
SN65HVD06DR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	VP06	Samples
SN65HVD06DRG4	ACTIVE	SOIC	D	8		TBD	Call TI	Call TI	-40 to 85		Samples
SN65HVD06P	ACTIVE	PDIP	P	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-40 to 85	65HVD06	Samples
SN65HVD06PE4	ACTIVE	PDIP	P	8		TBD	Call TI	Call TI	-40 to 85		Samples
SN65HVD07D	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	VP07	Samples
SN65HVD07DG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	VP07	Samples
SN65HVD07DR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	VP07	Samples
SN65HVD07DRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	VP07	Samples
SN65HVD07P	ACTIVE	PDIP	P	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-40 to 85	65HVD07	Samples

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
SN65HVD07PE4	ACTIVE	PDIP	P	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-40 to 85	65HVD07	Samples
SN75HVD05D	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	VN05	Samples
SN75HVD05DG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	VN05	Samples
SN75HVD05P	ACTIVE	PDIP	P	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	0 to 70	75HVD05	Samples
SN75HVD06D	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	VN06	Samples
SN75HVD06DR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	VN06	Samples
SN75HVD06P	ACTIVE	PDIP	P	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	0 to 70	75HVD06	Samples
SN75HVD07D	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	VN07	Samples
SN75HVD07DG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	VN07	Samples
SN75HVD07DR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	VN07	Samples
SN75HVD07DRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	VN07	Samples
SN75HVD07P	ACTIVE	PDIP	P	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	0 to 70	75HVD07	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

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TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

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⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

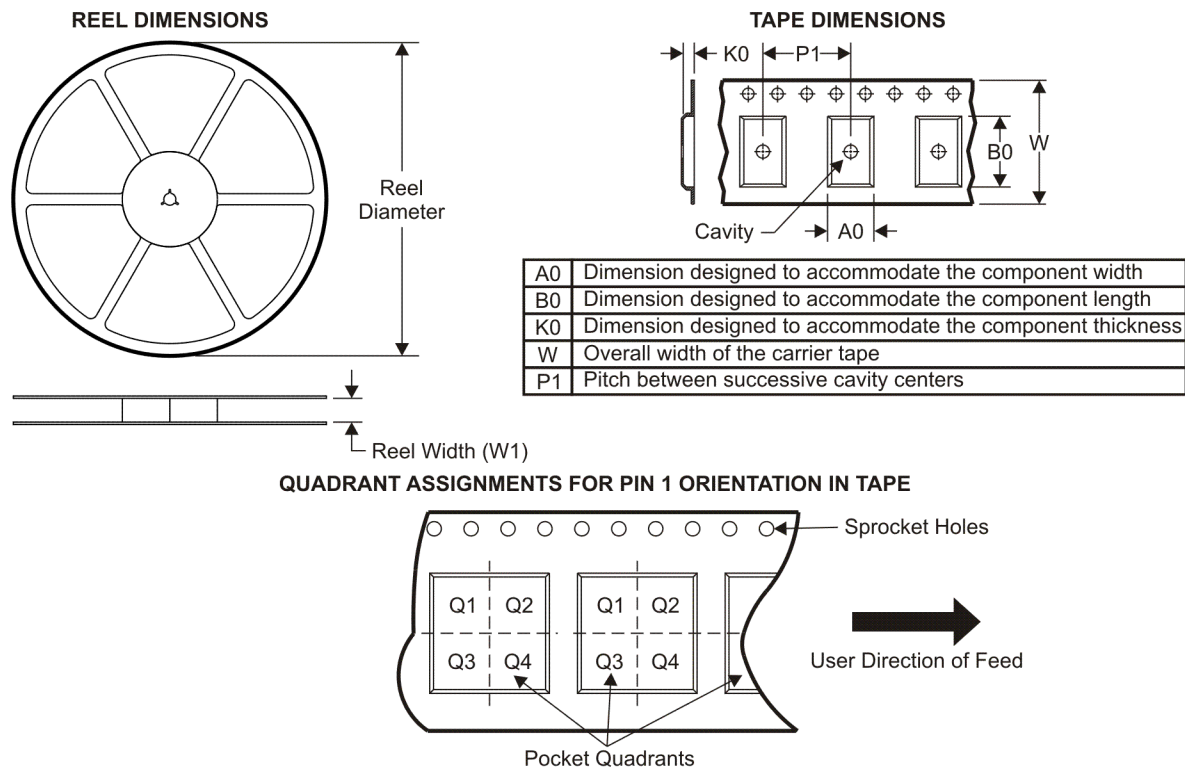
⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

⁽⁵⁾ Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

⁽⁶⁾ Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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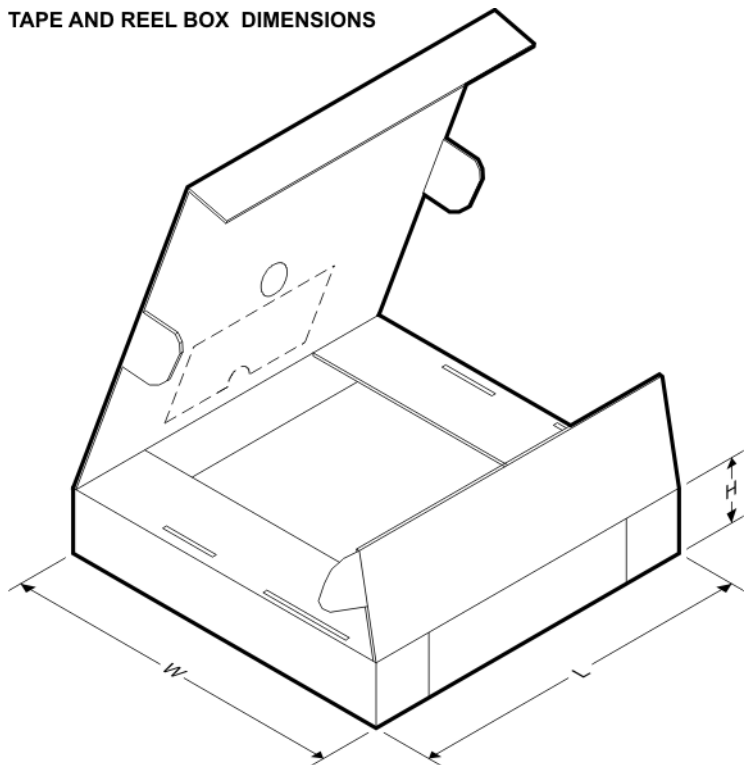
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*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN65HVD05DR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
SN65HVD06DR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
SN65HVD07DR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
SN75HVD06DR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
SN75HVD07DR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1

TAPE AND REEL BOX DIMENSIONS

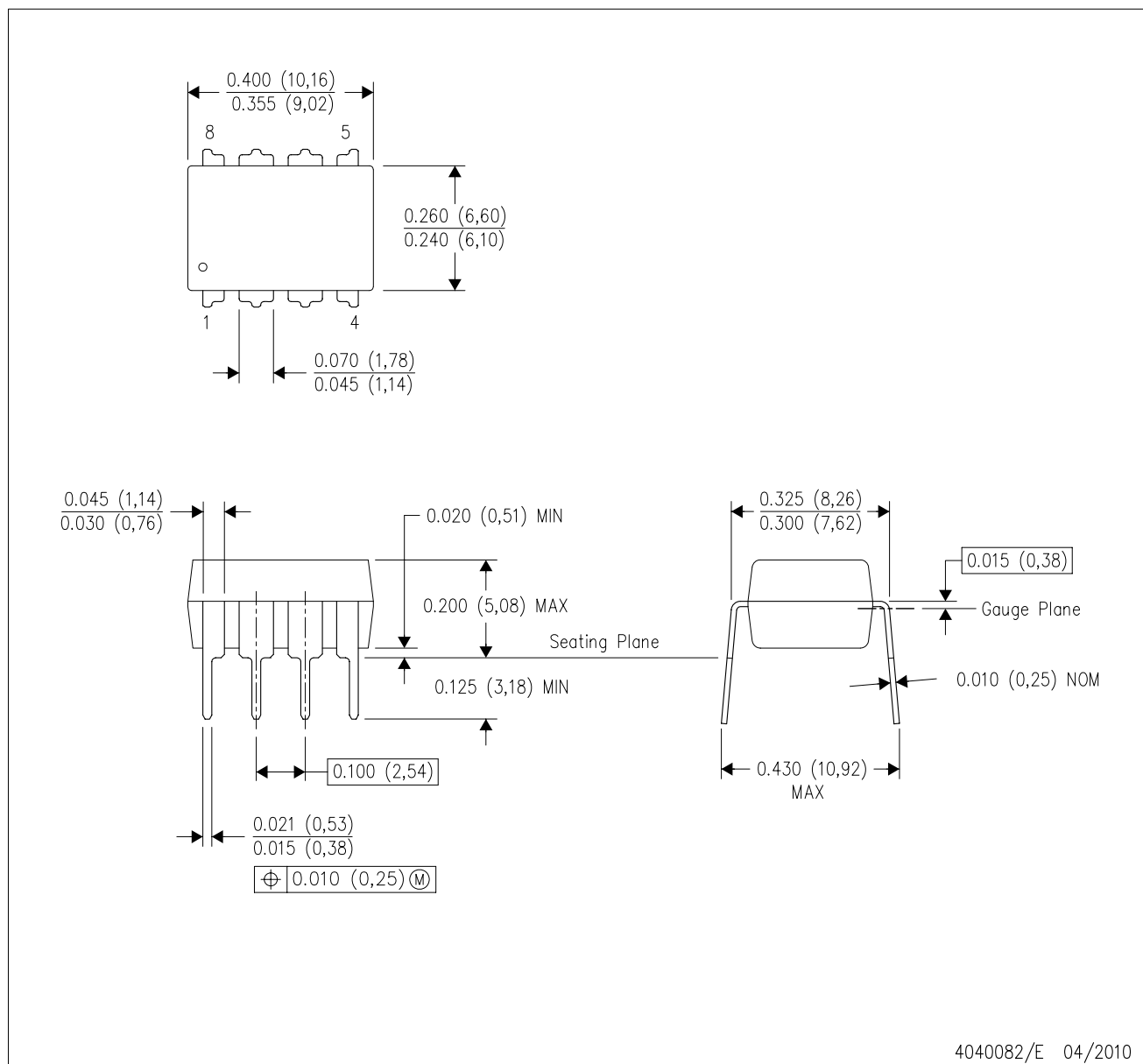


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN65HVD05DR	SOIC	D	8	2500	340.5	338.1	20.6
SN65HVD06DR	SOIC	D	8	2500	340.5	338.1	20.6
SN65HVD07DR	SOIC	D	8	2500	340.5	338.1	20.6
SN75HVD06DR	SOIC	D	8	2500	340.5	338.1	20.6
SN75HVD07DR	SOIC	D	8	2500	340.5	338.1	20.6

P (R-PDIP-T8)

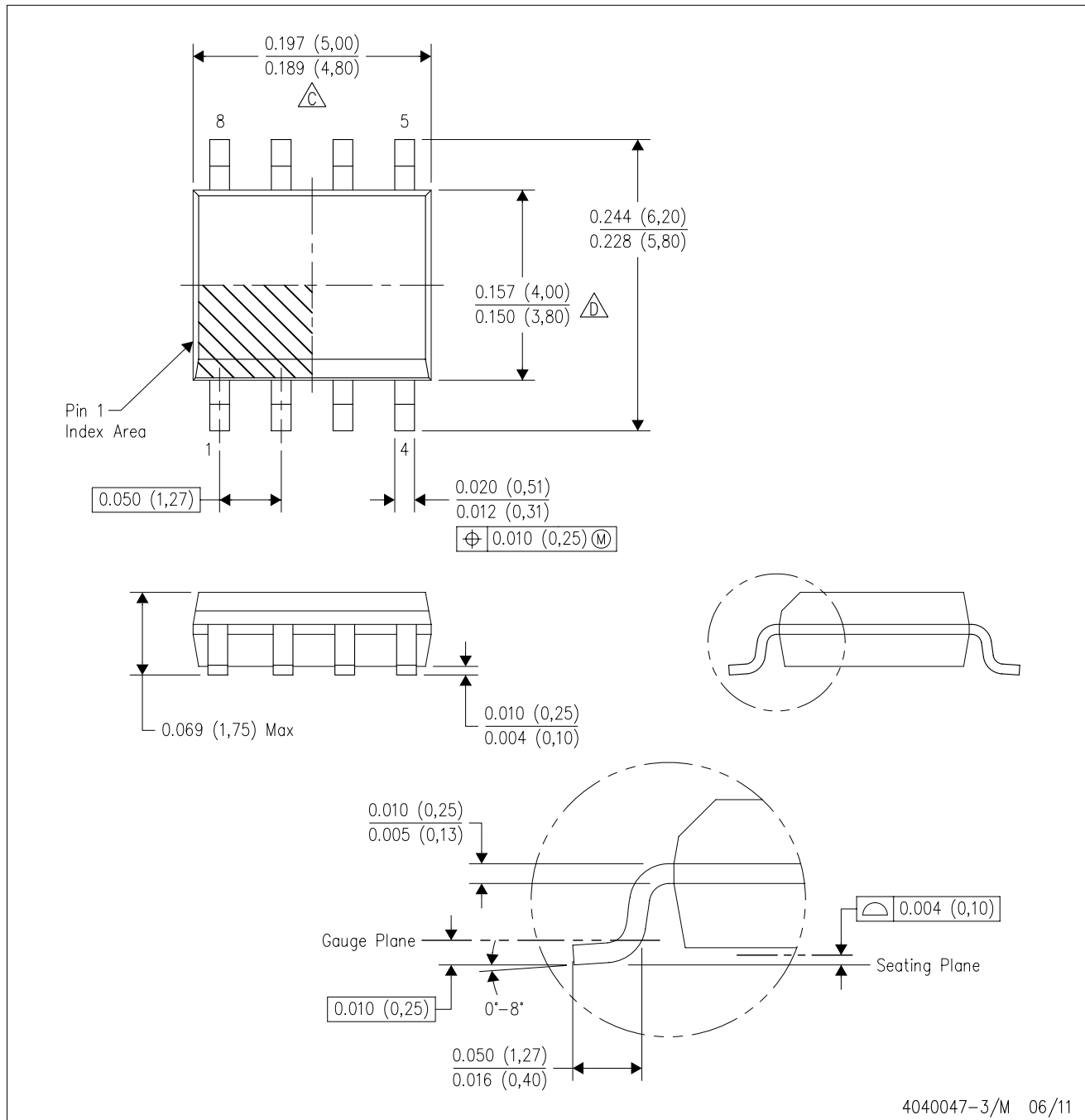
PLASTIC DUAL-IN-LINE PACKAGE



- NOTES:
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 - B. This drawing is subject to change without notice.
 - C. Falls within JEDEC MS-001 variation BA.

D (R-PDSO-G8)

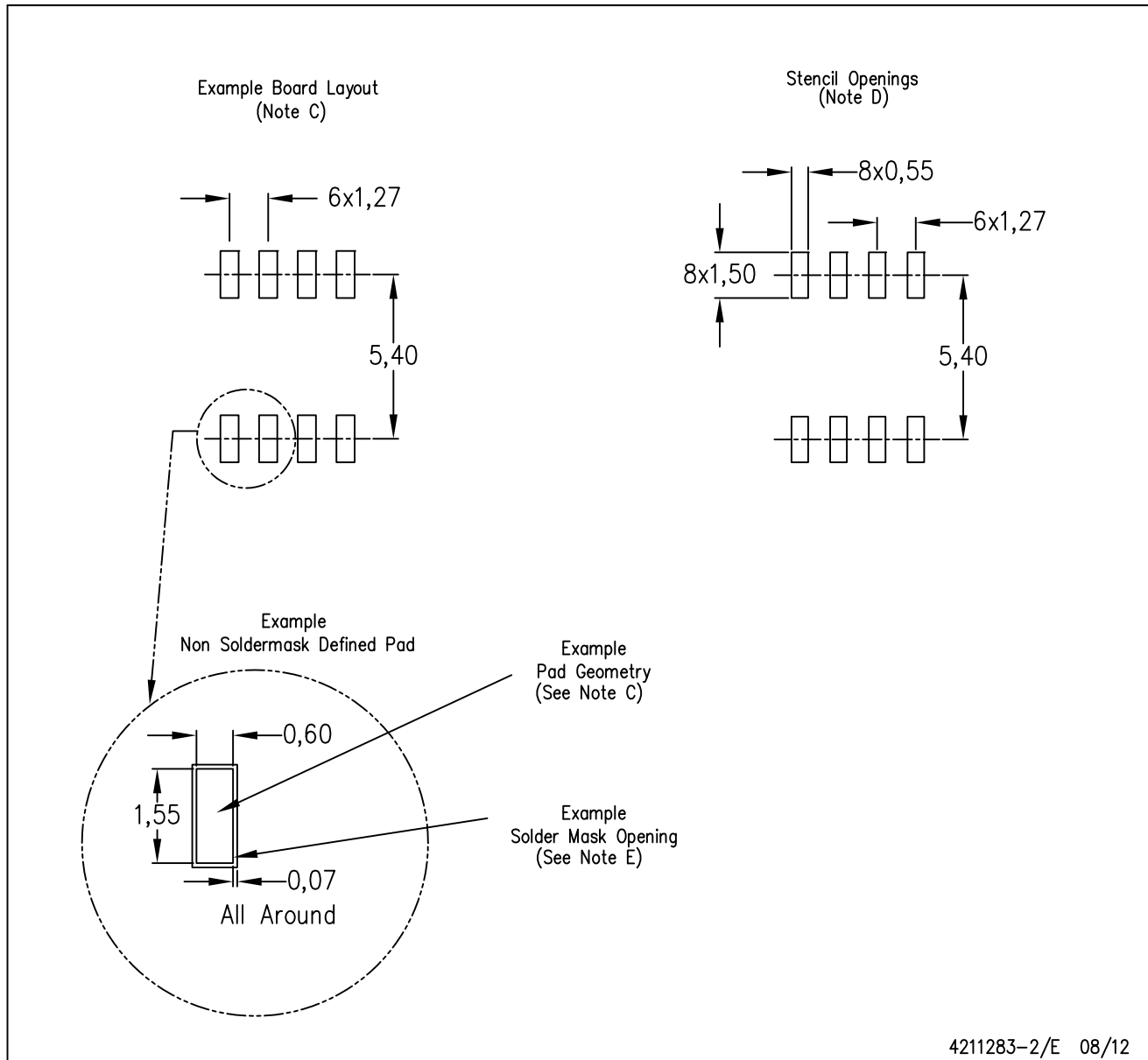
PLASTIC SMALL OUTLINE



- NOTES:
- A. All linear dimensions are in inches (millimeters).
 - B. This drawing is subject to change without notice.
 - $\triangle C$ Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
 - $\triangle D$ Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
 - E. Reference JEDEC MS-012 variation AA.

D (R-PDSO-G8)

PLASTIC SMALL OUTLINE



4211283-2/E 08/12

- NOTES:
- A. All linear dimensions are in millimeters.
 - B. This drawing is subject to change without notice.
 - C. Publication IPC-7351 is recommended for alternate designs.
 - D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
 - E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

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